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Renesas Technology Corp. Customer Support Dept. April 1, 2003



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Remember to give due consideration to safety when making your circuit designs, with appropriate
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# 2SC5022

# Silicon NPN Triple Diffused



ADE-208-896 (Z) 1st. Edition September 2000

### **Application**

High voltage amplifier

#### **Features**

• High breakdown voltage  $V_{(BR)CEO} = 1500 \text{ V Min}$ 

#### **Outline**

TO-220FM

1. Base
2. Collector
3. Emitter

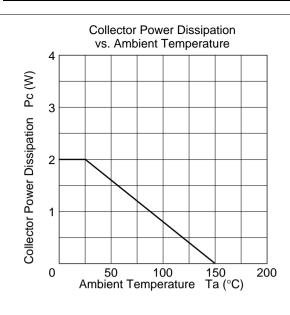
# 2SC5022

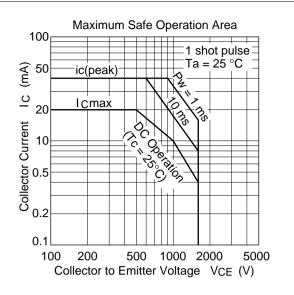
### **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

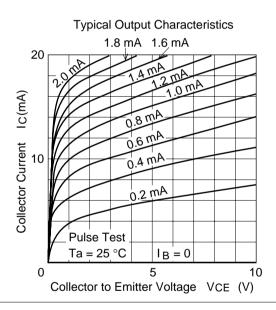
Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{CBO}$	1500	V
Collector to emitter voltage	$V_{\text{CEO}}$	1500	V
Emitter to base voltage	$V_{EBO}$	6	V
Collector current	I <sub>c</sub>	20	mA
Collector peak current	C (peak)	40	mA
Collector power dissipation	P <sub>c</sub>	2	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

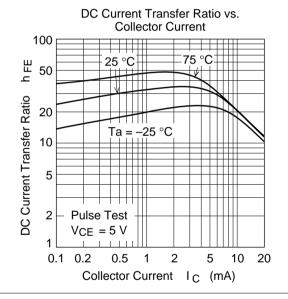
### **Electrical Characteristics** ( $Ta = 25^{\circ}C$ )

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector cutoff current	I <sub>CES</sub>	_	_	10	μΑ	$V_{CE} = 1500 \text{ V}, R_{BE} = 0$
Collector cutoff current	I <sub>CEO</sub>	_	_	100	μΑ	V <sub>CE</sub> = 1500 V, R <sub>BE</sub> =
Emitter cutoff current	I <sub>EBO</sub>	_	_	10	μΑ	$V_{EB} = 6 \text{ V}, I_{C} = 0$
DC current transfer ratio	h <sub>FE</sub>	10	_	_		$V_{CE} = 5 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V <sub>CE (sat)</sub>	_	_	5.0	V	$I_C = 10 \text{ mA}, I_B = 2 \text{ mA}$

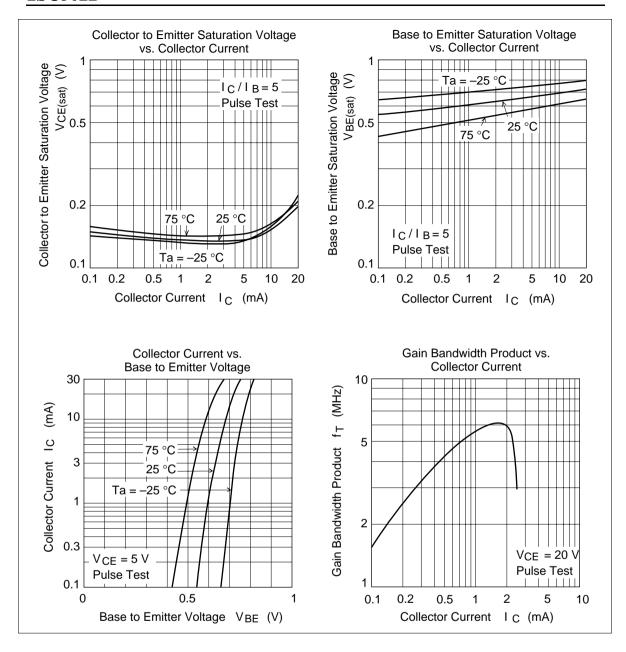


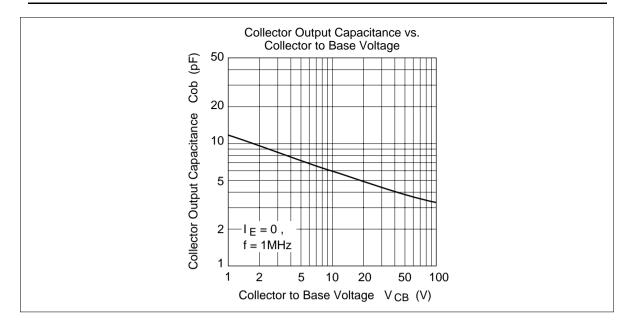






### 2SC5022





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